捷多邦,专业PCB打样工厂,24小时**SNATAQ**UCH32244 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES412B-SEPTEMBER 2002-REVISED JUNE 2005

FEATURES

- Member of the Texas Instruments Widebus+™
 Family
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t_{pd} of 1.8 ns at 1.8 V

- Low Power Consumption, 40-μA Max I_{CC}
- ±8-mA Output Drive at 1.8 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This 32-bit buffer/driver is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUCH32244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as eight 4-bit buffers, four 8-bit buffers, two 16-bit buffers, or one 32-bit buffer. It provides true outputs and symmetrical active-low output-enable (OE) inputs.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	LFBGA – GKE	Tape and reel	SN74AUCH32244GKER	MK244

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



PDPlease be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus+ is a trademark of Texas Instruments.



GKE PACKAGE (TOP VIEW)

A B C C C C C C C C C C C C C C C C C C		_	1	2	3	4	5	6
C	Α		\circ	\bigcirc	\bigcirc	\circ	\circ	\circ
D	В		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
E 000000 F 000000 G 000000 J 000000 K 000000 M 000000 P 000000	С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
F 000000 G 000000 H 000000 K 000000 K 000000 M 000000 P 000000	D		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
G	Е		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
H 000000 J 000000 K 000000 M 000000 N 000000 P 000000	F		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
J 000000 K 000000 L 000000 M 000000 P 000000 R 000000	G		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
K 000000 L 000000 M 000000 P 000000 R 000000	Н		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
L 000000 M 000000 N 000000 P 000000	J		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
M 000000 N 000000 P 000000	K		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
N 000000 P 000000 R 000000	L		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
P 000000 R 000000	М		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
R 000000	N		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
	Р		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
T 000000	R		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
`	Т		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc

TERMINAL ASSIGNMENTS

	1	2	3	4	5	6
Α	1Y2	1Y1	1 OE	2 OE	1A1	1A2
В	1Y4	1Y3	GND	GND	1A3	1A4
С	2Y2	2Y1	V _{CC}	V _{CC}	2A1	2A2
D	2Y4	2Y3	GND	GND	2A3	2A4
E	3Y2	3Y1	GND	GND	3A1	3A2
F	3Y4	3Y3	V _{CC}	V _{CC}	3A3	3A4
G	4Y2	4Y1	GND	GND	4A1	4A2
Н	4Y3	4Y4	4 OE	3 OE	4A4	4A3
J	5Y2	5Y1	5 OE	6 OE	5A1	5A2
K	5Y4	5Y3	GND	GND	5A3	5A4
L	6Y2	6Y1	V _{CC}	V _{CC}	6A1	6A2
М	6Y4	6Y3	GND	GND	6A3	6A4
N	7Y2	7Y1	GND	GND	7A1	7A2
Р	7Y4	7Y3	V _{CC}	V _{CC}	7A3	7A4
R	8Y2	8Y1	GND	GND 8A1		8A2
Т	8Y3	8Y4	8 OE	7 0E	8A4	8A3

FUNCTION TABLE (EACH 4-BIT BUFFER)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Н
L	L	L





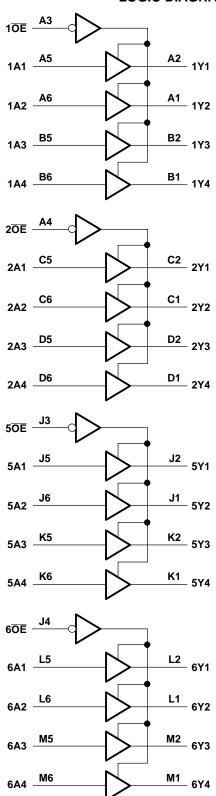
SCES412B-SEPTEMBER 2002-REVISED JUNE 2005

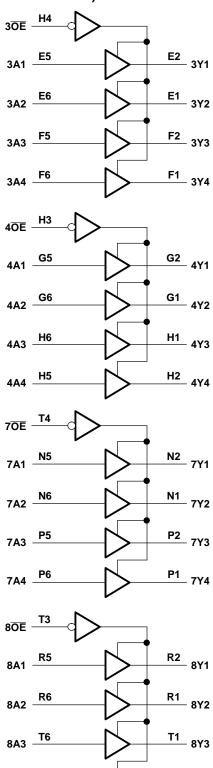
FUNCTION TABLE (EACH 4-BIT BUFFER) (continued)

INP	JTS	OUTPUT
ŌĒ	Α	Υ
Н	X	Z



LOGIC DIAGRAM (POSITIVE LOGIC)





T2 8Y4



SCES412B-SEPTEMBER 2002-REVISED JUNE 2005

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	3.6	V
VI	Input voltage range ⁽²⁾		-0.5	3.6	V
Vo	Voltage range applied to any output in the hig	h-impedance or power-off state ⁽²⁾	-0.5	3.6	V
Vo	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance ⁽³⁾			40	°C/W
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions⁽¹⁾

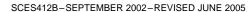
			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	2.7	V
		$V_{CC} = 0.8 \text{ V}$	V _{CC}		
V_{IH}	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V
		V_{CC} = 2.3 V to 2.7 V	1.7		
		$V_{CC} = 0.8 \text{ V}$		0	
V_{IL}	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0	.35 × V _{CC}	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
VI	Input voltage		0	3.6	V
V	Output voltage	Active state	0	V_{CC}	V
Vo	Output voltage	3-state	0	3.6	V
		$V_{CC} = 0.8 \text{ V}$		-0.7	
		V _{CC} = 1.1 V		-3	
I_{OH}	High-level output current	V _{CC} = 1.4 V		-5	mA
		V _{CC} = 1.65 V		8–	
		$V_{CC} = 2.3 \text{ V}$		-9	
		$V_{CC} = 0.8 V$		0.7	
		V _{CC} = 1.1 V		3	
I_{OL}	Low-level output current	V _{CC} = 1.4 V		5	mA
		V _{CC} = 1.65 V		8	
		$V_{CC} = 2.3 \text{ V}$		9	
		$V_{CC} = 0.8 \text{ V}$		20	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 1.3 \text{ V}$		15	ns/V
		V_{CC} = 1.6 V, 1.95 V, and 2.7 V		10	
T _A	Operating free-air temperature	·	-40	85	°C

⁽¹⁾ All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AUCH32244 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS





Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	UNIT	
	$I_{OH} = -100 \mu\text{A}$	0.8 V to 2.7 V	V _{CC} - 0.1				
	$I_{OH} = -0.7 \text{ mA}$	0.8 V		0.55			
	$I_{OH} = -3 \text{ mA}$	1.1 V	0.8			V	
V _{OH}	$I_{OH} = -5 \text{ mA}$	1.4 V	1			V	
	$I_{OH} = -8 \text{ mA}$	1.65 V	1.2				
	$I_{OH} = -9 \text{ mA}$	2.3 V	1.8				
	$I_{OL} = 100 \mu A$	0.8 V to 2.7 V			0.2		
	$I_{OL} = 0.7 \text{ mA}$	0.8 V		0.25			
V	I _{OL} = 3 mA	1.1 V			0.3	V	
V _{OL}	I _{OL} = 5 mA	1.4 V			0.4	V	
	I _{OL} = 8 mA	1.65 V			0.45		
	I _{OL} = 9 mA	2.3 V			0.6		
I _I A or \overline{OE} inputs	$V_I = V_{CC}$ or GND	0 to 2.7 V			±5	μΑ	
	V _I = 0.35 V	1.1 V	10				
1 (2)	V _I = 0.47 V	1.4 V	15				
I _{BHL} ⁽²⁾	V _I = 0.57 V	1.65 V	20			μА	
	V _I = 0.7 V	2.3 V	40				
	V _I = 0.8 V	1.1 V	-10				
(3)	V _I = 0.9 V	1.4 V	-15			^	
I _{BHH} ⁽³⁾	V _I = 1.07 V	1.65 V	-20			μΑ	
	V _I = 1.7 V	2.3 V	-40				
		1.3 V	75				
(4)	V = 0 to V	1.6 V	125				
I _{BHLO} ⁽⁴⁾	$V_I = 0$ to V_{CC}	1.95 V	175			μΑ	
		2.7 V	275				
		1.3 V	-75				
I _{BHHO} ⁽⁵⁾	$V_I = 0$ to V_{CC}	1.6 V	-125			^	
'BHHO'	VI = 0 to VCC	1.95 V	-175			μΑ	
		2.7 V	-275				
I _{off}	V_I or $V_O = 2.7 \text{ V}$	0			±10	μΑ	
I _{OZ}	$V_O = V_{CC}$ or GND	2.7 V			±10	μΑ	
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V			40	μΑ	
C _i	$V_I = V_{CC}$ or GND	2.5 V		3	4.5	pF	
C _o	$V_O = V_{CC}$ or GND	2.5 V		4	7	pF	

 ⁽¹⁾ All typical values are at T_A = 25°C.
 (2) The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND

and then raising it to V_{IL} max. The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to $V_{\rm CC}$ and then lowering it to $V_{\rm IH}$ min. An external driver must source at least $I_{\rm BHLO}$ to switch this node from low to high. An external driver must sink at least $I_{\rm BHHO}$ to switch this node from high to low.



SCES412B-SEPTEMBER 2002-REVISED JUNE 2005

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 0.8 V		V _{CC} = 1.2 V ± 0.1 V		1.5 V 1 V		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = ± 0.		UNIT
	(INFOT)	(0011-01)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t _{pd}	Α	Υ	5.4	0.8	2.8	0.6	1.9	0.7	1.3	1.8	0.5	1.8	ns
t _{en}	ŌĒ	Υ	8	1	4.4	0.7	2.6	8.0	1.4	2.5	0.6	1.9	ns
t _{dis}	ŌĒ	Y	12	1.9	4.9	1	4.6	1.5	2.6	4	0.5	2	ns

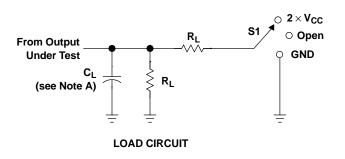
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETE	ER	TEST CONDITIONS	V _{CC} = 0.8 V TYP	V _{CC} = 1.2 V TYP	V _{CC} = 1.5 V TYP	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	UNIT
	Power dissipation	Outputs enabled	f = 10 MHz	21	22	23	25	30	۲
C _{pd}	capacitance	Outputs disabled	I = IO MINZ	1	1	1	1	1	pF

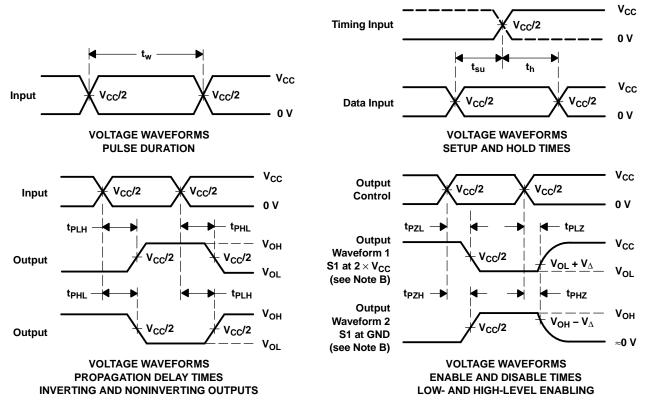


PARAMETER MEASUREMENT INFORMATION



TEST	S 1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2×V _{CC}
t _{PHZ} /t _{PZH}	GND

V _{CC}	CL	R _L	V_{Δ}
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	30 pF	500 Ω	0.15 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

30-Mar-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74AUCH32244GKER	ACTIVE	LFBGA	GKE	96	1000	TBD	SNPB	Level-3-220C-168 HR
SN74AUCH32244ZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-250C-168 HR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

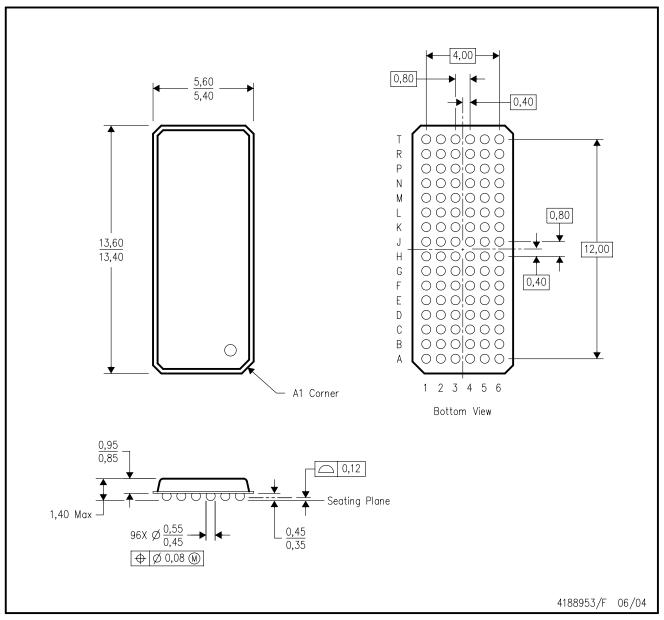
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



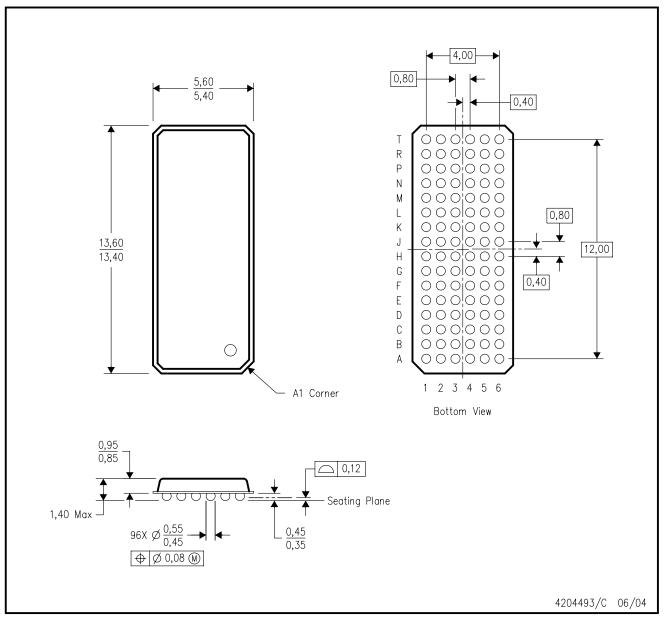
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is lead—free. Refer to the 96 GKE package (drawing 4188953) for tin—lead (SnPb).



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265